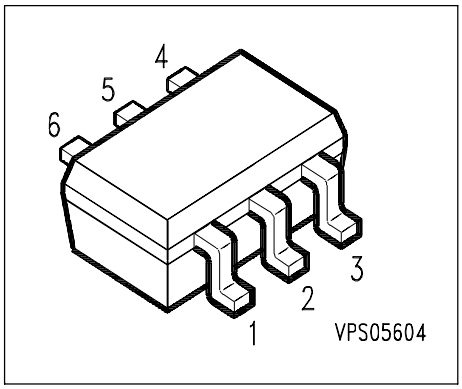
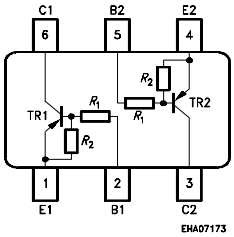
PNP Silicon Digital Transistor Array

- Switching circuit, inverter, interface circuit, driver circuit
- Built in resistor (R_1 = 10kΩ, R_2 = 10kΩ)





Type	Marking	Ordering Code	Pin Configuration						Package
BCR 183S	WMs	Q62702-C2377	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT-363

Maximum Ratings

Parameter	Symbol	Values	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	10	
Input on Voltage	$V_{i(on)}$	20	
DC collector current	I_C	100	mA
Total power dissipation, T_S = 115°C	P_{tot}	250	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	- 65 ... + 150	

Thermal Resistance

Junction ambient 1)	R_{thJA}	≤ 275	K/W
Junction - soldering point	R_{thJS}	≤ 140	

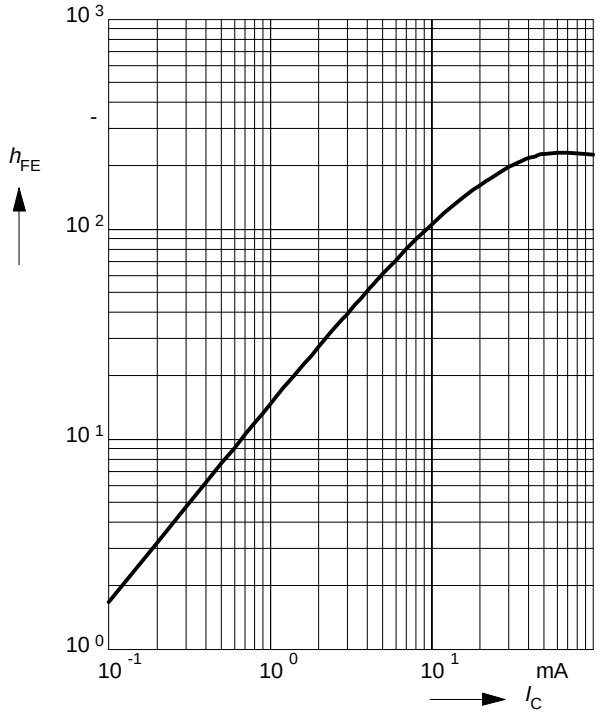
1) Package mounted on pcb 40mm x 40mm x 1.5mm / 0.5cm^2 Cu

Electrical Characteristics at T_A=25°C, unless otherwise specified

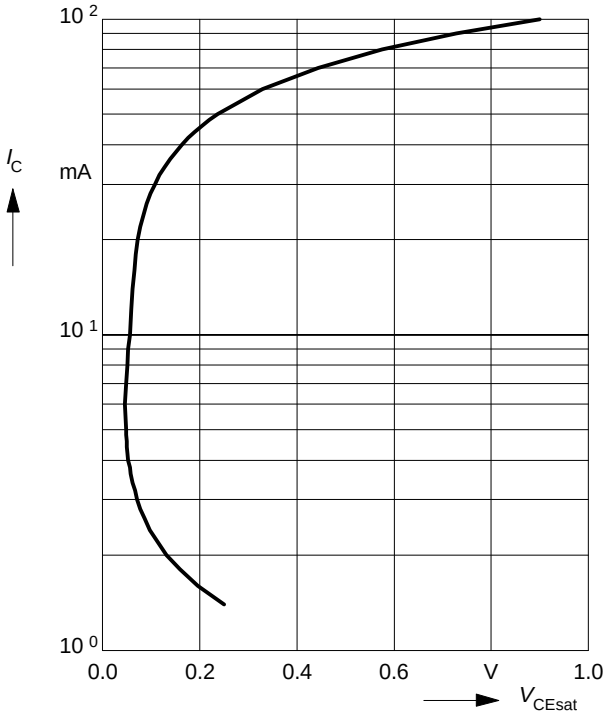
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage I_C = 100 µA, I_B = 0	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage I_C = 10 µA, I_B = 0	$V_{(BR)CBO}$	50	-	-	
Collector cutoff current V_{CB} = 40 V, I_E = 0	I_{CBO}	-	-	100	nA
Emitter cutoff current V_{EB} = 10 V, I_C = 0	I_{EBO}	-	-	0.75	µA
DC current gain I_C = 5 mA, V_{CE} = 5 V	h_{FE}	30	-	-	-
Collector-emitter saturation voltage 1) I_C = 10 mA, I_B = 0.5 mA	V_{CEsat}	-	-	0.3	V
Input off voltage I_C = 100 µA, V_{CE} = 5 V	$V_{i(off)}$	0.8	-	1.5	
Input on Voltage I_C = 2 mA, V_{CE} = 0.3 V	$V_{i(on)}$	1	-	2.5	
Input resistor	R_1	7	10	13	kΩ
Resistor ratio	R_1/R_2	0.9	1	1.1	-
AC Characteristics					
Transition frequency I_C = 10 mA, V_{CE} = 5 V, f = 100 MHz	f_T	-	200	-	MHz
Collector-base capacitance V_{CB} = 10 V, f = 1 MHz	C_{cb}	-	3	-	pF

1) Pulse test: t < 300µs; D < 2%

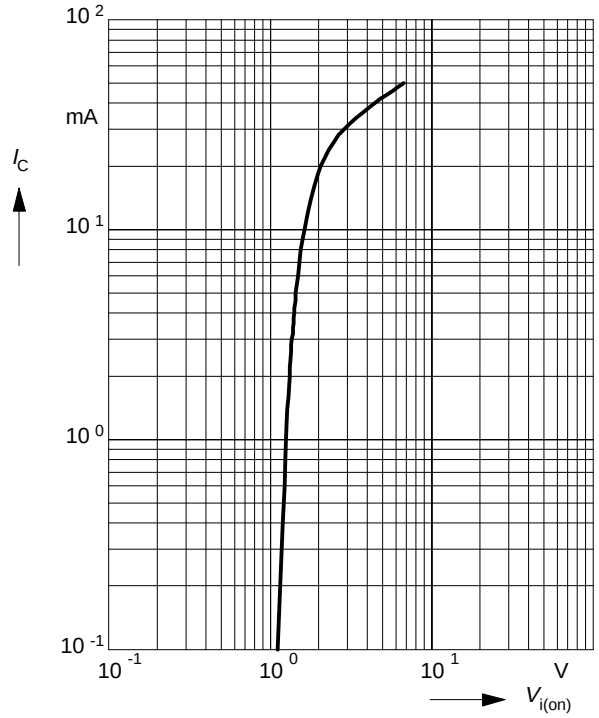
DC Current Gain $h_{FE} = f(I_C)$
V_{CE} = 5V (common emitter configuration)



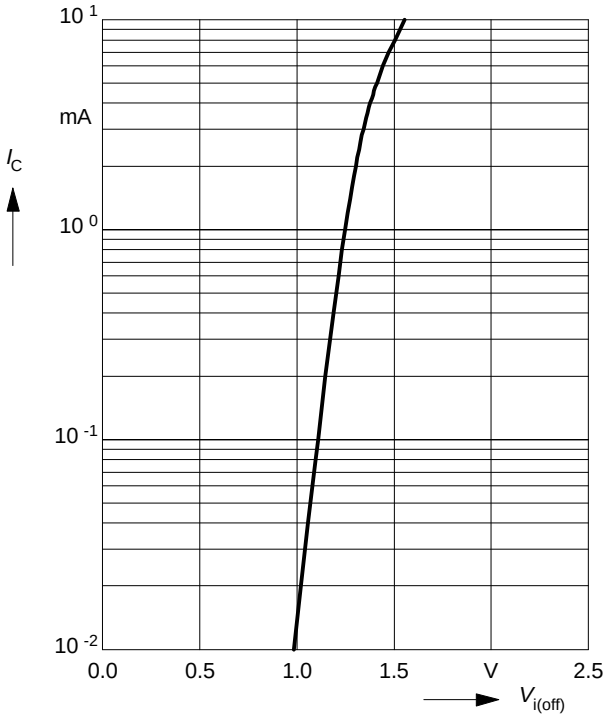
Collector-Emitter Saturation Voltage
$V_{CEsat} = f(I_C)$, h_{FE} = 20



Input on Voltage $V_{i(on)} = f(I_C)$
V_{CE} = 0.3V (common emitter configuration)

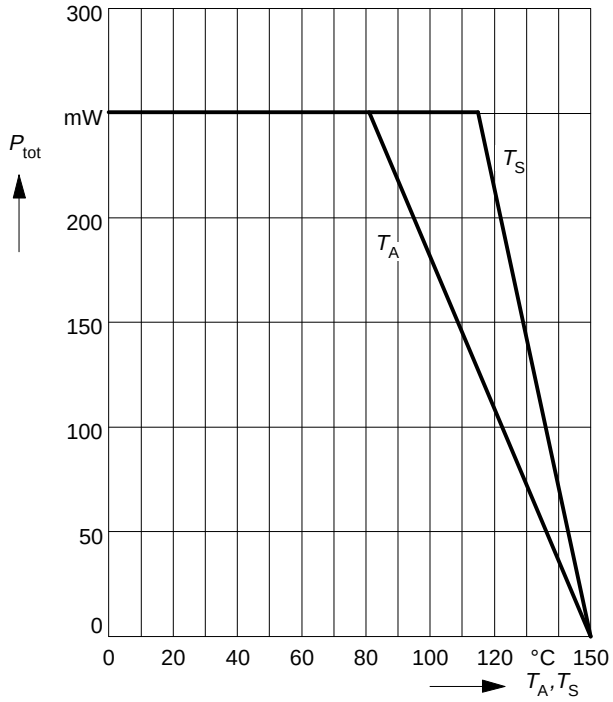


Input off voltage $V_{i(off)} = f(I_C)$
V_{CE} = 5V (common emitter configuration)

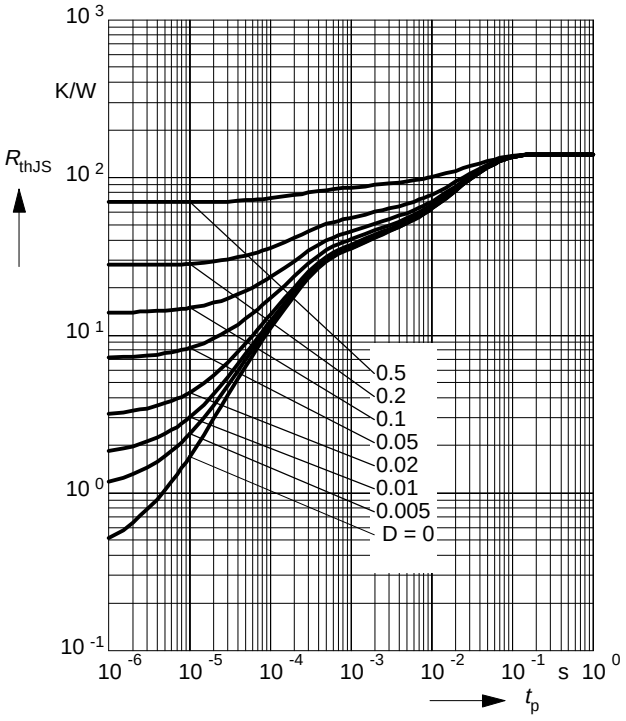


Total power dissipation $P_{tot} = f(T_A^*; T_S)$

* Package mounted on epoxy



Permissible Pulse Load $R_{thJS} = f(t_p)$



Permissible Pulse Load $P_{totmax} / P_{totDC} = f(t_p)$